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# High-energy x-ray diffraction study of amorphous $(Si_{0.71}Ge_{0.29})O_2$

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#### Abstract

Synthetic amorphous  $(Si_{0.71}Ge_{0.29})O_2$  has been investigated by high-energy synchrotron x-ray diffraction (E = 130.1 keV), in order to achieve a better understanding of amorphous structures built from the two network-forming oxides SiO<sub>2</sub> and GeO<sub>2</sub>. The interatomic distances and bond angles that were determined are predominantly the same as in pure a-SiO<sub>2</sub> and a-GeO<sub>2</sub>, respectively. According to the first coordination shell, the total coordination number CN(TO) = 3.4(5) (T = Si, Ge) indicates the existence of a considerable amount of cations that are connected to less than four oxygen ions. This result is clearly different with respect to the coordinations found in the structures of the respective pure amorphous oxides. If the second coordination shell is also taken into account, a second average (Ge-O) interatomic distance at r = 2.23(1) Å can be determined and CN(TO) increases to 4.2(1.1), indicating that all cations are actually connected to four anions. However, regular [GeO<sub>4</sub>] tetrahedra are no longer supposed to be the only possible germanium-oxygen coordination polyhedra in the structure investigated. Based on these findings, we infer that  $SiO_2$  and  $GeO_2$  predominantly form a homogeneous but not completely continuous random network.

## 1. Introduction

In the past six years, essential progress has been made possible in determining the structure of amorphous  $GeO_2$  [1–7]. The results indicate that the glass structure of  $GeO_2$  can be

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described by a continuous random network of corner-sharing  $[GeO_4]$  tetrahedra. A similar structure model has been proposed for amorphous silica [8-12]. Germano-silicate glasses are widely used as, for example, optical fibres, and much research has been done on the physical (i.e. optical) properties of such fibres. However, surprisingly little is known about the structure of germano-silicate glasses [13-23], even though this knowledge is essential for a comprehensive understanding of the material properties.

The aim of this study is to find out whether the structure of germano-silicate glass forms a homogeneous network, similar to the structure of pure amorphous silica and germania, respectively. To this end we performed x-ray diffraction experiments on a germano-silicate glass containing 29 mol% GeO<sub>2</sub>. We used high-energy synchrotron x-ray diffraction (E = 130.1 keV) to achieve a resolution in direct space that enables the reliable determination of average interatomic distances, bond angles and coordination numbers. The Ge content of our sample is somewhat higher than in most conventional optical fibres, since we intended to perform further high-quality diffraction experiments on the same sample using resonant scattering at the Ge K-absorption edge, in order to gain additional information about the local environment of germanium. The results of these AWAXS experiments will be presented in a forthcoming paper.

#### 2. Experimental details

#### 2.1. Sample preparation

Mixtures of ultra-pure amorphous SiO<sub>2</sub> and ultra-pure amorphous GeO<sub>2</sub> powder, respectively, were homogenized and melted in a covered Pt/Rh crucible at a temperature of 1750 °C. This temperature was kept constant for two days before the melt was quenched by simply pouring it on a cold steel plate. The solid sample was crushed, ground up and heat-treated for two days in a dry atmosphere at T = 120 °C to keep hydration as low as possible. The chemical composition and the homogeneity were determined by ICP-OES (inductive coupled plasma optical emission spectroscopy) and by laser ablation ICP-MS (inductive coupled plasma mass spectrometry). The average ratio of Si:Ge amounted to 26.92 ± 0.36:28.82 ± 0.15 wt%, and the distribution of both elements was homogeneous. The atomic density is 0.0664±0.0001 atoms Å<sup>-3</sup>, which is in good agreement with data in the literature [24].

## 2.2. High-energy x-ray diffraction (HXD)

The sample was investigated by HXD (E = 130.1 keV) at the BW5 wiggler synchrotron beamline at HASYLAB/DESY (Germany) using a Si(111) Laue single-crystal incident-beam monochromator [25]. Hard x-rays were used because a high resolution in real space, as desired for disordered materials, can be achieved and the required data corrections are small, particularly for absorption. Due to the small scattering angles, even the polarization correction is almost negligible [10]. The experiments were carried out in the Debye–Scherrer geometry. The sample holder was a pure silica glass capillary with a wall thickness of 0.01 mm and a diameter of 3.0 mm. The sample was placed in a vacuum chamber (with p = 0.012 mbar) to reduce significantly the air scattering at low values of Q ( $=4\pi \sin \Theta/\lambda$ ). Data were recorded in a range of Q between 0.45 and 32.27 Å<sup>-1</sup> (with a stepwidth = 0.039 Å<sup>-1</sup>). The total data acquisition time at each step was 120 s, and data were recorded in 12 separate scans (at 10 s/step) to minimize the influence of beam fluctuations and drifts in general. The effective absorption coefficient,  $\mu(E)$ , was determined from sample transmission experiments. The maximum absorption at E = 130.1 keV is only 9.8% for the low-density sample that was investigated. Counting statistics yielded relative errors of  $|\Delta I/I| = 0.06\%$  obtained at  $Q_{\text{max}}$ .



**Figure 1.** Fully corrected and normalized intensity data,  $I^{coh}(Q)$  (for E = 130.1 keV). The full curve shows experimental data; the dashed curve shows the isotropic part of the scattering intensity (self-scattering + Compton scattering). The inset is a magnified view of the high-Q region.

The data reduction included corrections for background scattering, scattering of the empty capillary, dead time, polarization, absorption, inelastic scattering (Compton) [26] and the variable sample–detector distance, which is caused by a linear movement in the Ge solid-state detector normal to the primary beam. After data reduction, the scattering intensities were normalized to electron units [27–30] (figure 1). For the calculation of the independent coherent scattering intensities, the analytical scattering-factor functions for free ions of Waasmaier and Kirfel [31] were used.

# 3. Results

The average interatomic distances  $r_{ij}$  (Å) that were determined by HXD are summarized in table 1. The values of the  $r_{ij}$  and the associated uncertainties were calculated from the total pair correlation function, G(r), and the radial distribution function, RDF:

$$G(r) = \frac{2}{\pi} \int_0^\infty Q[S^{\text{FZ}}(Q) - 1] M(Q) \sin(Qr) \, \mathrm{d}Q \tag{1}$$

$$RDF = r[G(r) + 4\pi r\rho_0]$$
(2)

where  $S^{FZ}(Q)$  denotes the Faber–Ziman (FZ) total structure factor [32, 33],  $\rho_0$  is the atomic density, and M(Q) is a smoothing function [34] that reduces truncation effects in the Fourier transform G(r). In table 1, the  $r_{ij}$  (Å) are also compared to the corresponding interatomic distances in a-SiO<sub>2</sub> and a-GeO<sub>2</sub>. These distances represent the mean values that were calculated exclusively from x-ray diffraction data for a-SiO<sub>2</sub> [8, 10, 11, 35, 36] and a-GeO<sub>2</sub> [1, 2, 7, 37–40], respectively, except the first O–O correlation for a-GeO<sub>2</sub>, which has been taken from neutron diffraction results [40]. Figure 2 shows the interference function  $Q[S^{FZ}(Q) - 1]$  and figure 3 shows the related total pair correlation function G(r). Figure 4 depicts the 1.4–3.6 Å range of the total RDF (first-neighbour distances), which was fitted by a linear combination of



**Figure 2.** The interference function  $Q[S^{FZ}(Q) - 1]$ , where  $S^{FZ}(Q)$  denotes the total FZ structure factor [32, 33]: bold curve—smoothed function; thin curve—unsmoothed function.

six variable Gaussian functions whose final parameters are summarized in table 2. The total coordination number CN(TO) = 3.4(5) (T = Si, Ge) indicates the existence of a considerable amount of cations that are connected to less than four anions, contrary to the coordinations found in the structures of the pure oxide glasses. The partial coordination numbers  $CN_{ij}$  given in table 2 must be handled with care, because it is usually not advisable to calculate partial coordination numbers from the total RDF of a ternary system. Therefore, the values in table 2 can only serve as a hint that the total coordination number CN(TO) < 4.0 is mainly caused by a reduced germanium–oxygen coordination. However, if the third maximum in the total RDF (second coordination shell) is considered as a second average (Ge–O) interatomic distance, then CN(TO) increases to 4.2(1.1) and, on average, all cations are connected to four oxygen coordination polyhedra.

Ge is known to form hexa-coordinated environments in oxide crystals [41, 42], so we considered the possibility that part of the Ge atoms assume a hexa-coordinated environment as a result of the stress induced by the presence of a SiO<sub>2</sub> matrix. This hypothesis was dismissed for the following reasons. The Ge–O distance in Rutile-type GeO<sub>2</sub> is, at 1.87–1.90 Å, considerably smaller than the peak distance observed. So far, six-fold coordinated Ge has been observed only in binary oxide samples that have undergone some kind of pressure treatment. This is not the case for our sample.

It is noted that similar peaks at  $r \approx 2.2$  Å were also found in other germanate glasses [43, 44] and were not assigned to interatomic correlations. Therefore, we also considered the possibility that the maximum at r = 2.23(1) Å might be just an artefact of the Fourier transformation of unknown origin. In this case, the peak must not be assigned to any interatomic correlation. But, with respect to the calculated coordination numbers, this seems to us to be the less likely possibility.

According to the  $r_{ij}$  given in table 1, the calculated bond angle (O–Si–O) = 107.4(1.8)° is comparable to the corresponding average bond angle in a-SiO<sub>2</sub> [ $\langle$ (O–Si–O) $\rangle$  = 109.5°].



**Figure 3.** The total pair correlation function G(r).



**Figure 4.** Part of the radial distribution function RDF (first-neighbour distances), fitted by six Gaussian functions: full circles—experimental; solid curve—overall fit; points—single Gaussian functions. The inset shows a larger part of the experimental RDF, starting at r = 0 Å.

Because r(O-O) = 2.63 Å is significantly smaller in  $a-(Si_{0.71}Ge_{0.29})O_2$  than in  $a-GeO_2$  ( $\langle r(O-O) \rangle = 2.84$  Å; see table 1), the (O–Ge–O) bond angle is calculated to be 98.1(1.3)° for  $a-(Si_{0.71}Ge_{0.29})O_2$ , which is clearly different from 109.9° in  $a-GeO_2$ .

**Table 1.** Interatomic distances,  $r_{ij}$  (Å), compared to the corresponding mean distances in a-SiO<sub>2</sub> [8, 10, 11, 35, 36] and a-GeO<sub>2</sub> [1, 2, 7, 37–40], respectively. T = Si, Ge. Standard deviations are given in parentheses.

a-(Si <sub>0.71</sub> Ge <sub>0.29</sub> )O <sub>2</sub>	$\langle a\text{-}SiO_2\rangle$	$\langle a\text{-}GeO_2\rangle$	Correlation
1.629(17)	1.613		Si–O
1.738(15)		1.734	Ge–O
2.229(9)			Ge–O
2.626(2)	2.64	2.84	0–0
3.095(2)	3.09	3.18	T-T
4.12(1)	4.15	4.11	Т-О
4.72(1)		4.88	Т-О
5.27(1)	5.10	4.96/5.38	Т-Т, Т-О, О-О
6.00(1)		6.00	T-T
6.50(2)	6.40		Т-О
7.17(1)			Т-Т, Т-О, О-О
9.55(3)			Т-Т, Т-О, О-О

**Table 2.** The parameters of the Gaussian functions, obtained from a fit of the first-neighbour distances.  $CN_{ij}$  denotes partial coordination numbers, which must be considered with care (see text).  $\langle u^2 \rangle = (FWHM^2/8 \ln 2)$  is the mean-square variation in  $r_{ij}$  (where FWHM is the full width at half maximum). T = Si, Ge. Standard deviations are given in parentheses.

Correlation	$CN_{ij}$	$r_{ij}$ (Å)	FWHM	$\langle u^2\rangle^{1/2}$
Si–O	4.7(1.0)	1.629(17)	0.2055(144)	0.087
Ge–O	1.9(1.0)	1.738(15)	0.1625(149)	0.069
Ge–O	1.7(0.1)	2.229(9)	0.3557(197)	0.151
0–0	5.0(0.2)	2.626(2)	0.2956(71)	0.126
T-T	5.9(0.1)	3.095(2)	0.3552(40)	0.151

# 4. Discussion

The structure of  $a-(Si_{0.71}Ge_{0.29})O_2$  reveals a well developed short-range and medium-range order with detectable interatomic distances up to 9.55 Å. The first-neighbour distances (tables 1 and 2; figure 4) are comparable to the  $r_{ij}$  found in a-SiO<sub>2</sub> and a-GeO<sub>2</sub>, respectively, with the exception of the clearly shorter O-O distance in a-GeO<sub>2</sub>. Therefore, the conclusion appears reasonable that the short-range order around Si is nearly identical to that in  $a-SiO_2$ , i.e.  $[SiO_4]$ tetrahedra are basic building units. The local environment of Ge, however, differs from that in a-GeO2. The [GeO4] tetrahedra are no longer regular. The existence of non-bridging oxygen ions could explain the shorter mean O-O distance as well as the smaller average (O-Ge-O) bond angle. The reduced germanium-oxygen coordination in the first shell, which has been addressed in the previous chapter, leads to the next assumption that a considerable number of Ge cations may be connected to only three or two anions. Consequently, direct Ge-Ge bonds are very likely to be present in the structure. Direct Ge-Si and Si-Si bonds can be excluded with high certainty due to the ideal short-range order around Si, as mentioned above. Bernard et al [22] concluded, from molecular dynamics (MD) simulations performed on a doped germano-silicate glass (Ge/Si = 1; 1.17 mol%  $Eu^{3+}$ ), that the lower Ge–O bond energy enables the structure to be more flexible around Ge. Our results provide additional supporting evidence for this assumption. The  $r_{ii}$  calculated by Bernard *et al* [22] are r(Si-O) = 1.62 Å and r(Ge–O) = 1.70 Å—the first distance is close to our results (tables 1 and 2). But there are also inconsistencies with the diffraction results. Bernard et al [22] assumed that exclusively regular tetrahedra were present in the structure (CN(SiO) = CN(GeO) = 4) and that a homogeneous distribution of the tetrahedra formed a three-dimensional network. According to our sample, this structure model is not very likely, though the MD results are partly supported by Raman experiments performed by Duverger *et al* [18, 19] on amorphous GeO<sub>2</sub>–SiO<sub>2</sub> waveguides. These authors also assume a homogeneous distribution of regular [SiO<sub>4</sub>] and [GeO<sub>4</sub>] tetrahedra, with Si–O–Si, Si–O–Ge and Ge–O–Ge bonds, forming a mixed network rather than phase segregation. However, we consider the maximum in the total RDF at r = 2.23(1) Å (figure 4) to be a second average (Ge–O) interatomic distance. Therefore, on average, all cations are connected to four anions, but the network is not only formed by regular tetrahedra.

In discussing different structure models for germano-silicate glasses, one must however keep in mind that all the samples that have been investigated so far [13–23] were prepared differently. Our sample was prepared directly from the melt; other samples were prepared via the sol–gel route, by CVD or by MCVD. Some samples were additionally heat-treated at higher temperatures, hydrated or UV irradiated. The effect of sample preparation on the structure of amorphous germano-silicates is not yet really understood and therefore experimental results received from different samples should be interpreted with care.

# 5. Conclusion

The aim of this study is a better understanding of amorphous structures built from the two network-forming oxides  $SiO_2$  and  $GeO_2$ . To this end, we performed x-ray diffraction experiments on amorphous (Si<sub>0.71</sub>Ge<sub>0.29</sub>)O<sub>2</sub> using high-energy synchrotron x-ray diffraction to achieve a high resolution in direct space. The results allow for the determination and identification of most of the interatomic distances in the range between 1.61 and 9.55 Å and for the concomitant calculation of some coordination numbers and bond angles. A clearly developed short-range and medium-range order can be noticed, exhibiting some structural features different to those of a-SiO<sub>2</sub> and a-GeO<sub>2</sub>. The interatomic distances that were determined are predominantly the same as in pure a-SiO<sub>2</sub> and a-GeO<sub>2</sub>, respectively. The total coordination number, according to the first coordination shell CN(TO) = 3.4(5) (T = Si, Ge), indicates the existence of a considerable number of cations that are connected to less than four oxygen ions. This result is clearly different to the coordinations found in the structures of the pure amorphous oxides. If the second coordination shell is also taken into account, then a second average (Ge–O) interatomic distance at r = 2.23(1) Å can be determined and CN(TO)increases to 4.2(1.1), indicating that all cations are actually connected to four anions. However, regular [GeO<sub>4</sub>] tetrahedra are no longer supposed to be the only possible germanium–oxygen coordination polyhedra in the structure that was investigated. Based on these findings, we infer that SiO<sub>2</sub> and GeO<sub>2</sub> predominantly form a homogeneous but not completely continuous random network.

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#### References

- [1] Neuefeind J and Liss K-D 1996 Ber. Bunsenges. Phys. Chem. 100 1341
- [2] Price D L, Saboungi M-L and Barnes A C 1998 Phys. Rev. Lett. 81 3207

- [3] Hussin R, Dupree R and Holland D 1999 J. Non-Cryst. Solids 246 159
- [4] Kang S, Park C, Saito M and Waseda Y 1999 Mater. Trans. 40 552
- [5] Wefing S 1999 J. Non-Cryst. Solids 244 89
- [6] Wefing S 1999 J. Non-Cryst Solids 244 112
- [7] Waseda Y and Sugiyama K 2000 Physics Meets Mineralogy ed H Aoki, Y Syono and R J Hemley (Cambridge: Cambridge University Press) p 354
- [8] Mozzi R L and Warren B E 1969 J. Appl. Crystallogr. 2 164
- [9] Konnert J H and Karle J 1973 Acta Crystallogr. A 29 702
- [10] Poulsen H F, Neuefeind J, Neumann H-B, Schneider J R and Zeidler J D 1995 J. Non-Cryst. Solids 188 63
- [11] Wright A C 1994 J. Non-Cryst. Solids 179 84
- [12] Wright A C and Sinclair R N 2000 Structure and Imperfections in Amorphous and Crystalline Silicon Dioxide ed R A B Devine, J-P Duraud and E Doorryhée (New York: Wiley) p 121
- [13] Kosugi T, Kobayashi H and Kogure Y 1996 Physica B 219/220 261
- [14] Schurman M K and Tomozawa M 1996 J. Non-Cryst. Solids 202 93
- [15] Liu F X, Qian J Y, Liu L and Ming H 1997 Phys. Rev. B 56 3066
- [16] Kawamura K, Kameshima Y, Hosono H and Kawazoe H 1998 Mater. Sci. Eng. B 54 18
- [17] Busani T, Plantier H, Devine R A B, Hernandez C and Campidelli Y 1999 J. Non-Cryst. Solids 254 80
- [18] Duverger C, Turell S, Bouazaoui M, Tonelli F, Montagna M and Ferrari M 1998 Phil. Mag. B 77 363
- [19] Duverger C, Nedelec J-M, Benatsou M, Bouazaoui M, Capoen B, Ferrari M and Turell S 1999 J. Mol. Struct. 480/481 169
- [20] Plotnichenko V G, Sokolov V O and Dianov E M 2000 J. Non-Cryst. Solids 278 85
- [21] Plotnichenko V G, Rybaltovskii A O, Sokolov V O, Koltashev V V, Malosiev A R, Popov V K and Dianov E M 2001 J. Non-Cryst. Solids 281 25
- [22] Bernard C, Chaussedent S, Monteil A, Balu N, Obriot J, Duverger C, Ferrari M, Bouazaoui M, Kinowski C and Turell S 2001 J. Non-Cryst. Solids 284 68
- [23] Fitting H-J, Barfels T, Trukhin A N and Schmidt B 2001 J. Non-Cryst. Solids 279 51
- [24] Nasu H, Sugimoto O, Matsuoka J and Kamiya K 1995 J. Non-Cryst. Solids 182 321
- [25] Schlenz H, Neuefeind J and Schmidt H 2000 HASYLAB Annual Report p 593
- [26] Balyuzi H M 1975 Acta Crystallogr. A 31 600
- [27] Krogh-Moe J 1956 Acta Crystallogr. 9 951
- [28] Norman N 1957 Acta Crystallogr. 10 370
- [29] Gingrich N S 1943 Rev. Mod. Phys. 15 90
- [30] Rahman A 1965 J. Chem. Phys. 42 3540
- [31] Waasmaier D and Kirfel A 1995 Acta Crystallogr. A 51 416
- [32] Faber T E and Ziman J M 1965 Phil. Mag. 11 153
- [33] Waseda Y 1980 The Structure of Non-Crystalline Materials (New York: McGraw-Hill)
- [34] Lorch E A 1969 J. Phys. C: Solid State Phys. 2 229
- [35] Johnson P A V, Wright A C and Sinclair R N 1983 J. Non-Cryst. Solids 58 109
- [36] Petkov V, Billinge S J L, Shastri S D and Himmel B 2000 Phys. Rev. Lett. 85 3436
- [37] Leadbetter A J and Wright A C 1972 J. Non-Cryst. Solids 7 37
- [38] Bondot P 1974 Acta Crystallogr. A **30** 470 Bondot P 1974 Phys. Status Solidi a **22** 511
- [39] Matsuraba E, Harada K, Waseda Y and Iwase M 1988 Z. Naturf. a 43 181
- [40] Price D L, Ellison A J G, Saboungi M-L, Hu R-Z, Egami T and Howells W S 1997 Phys. Rev. B 55 11249
- [41] Baur W H and Khan A A 1971 Acta Crystallogr. B 27 2133
- [42] Bolzan A A, Fong C, Kennedy B J and Howard C J 1997 Acta Crystallogr. B 53 373
- [43] Hoppe U, Kranold R, Weber H-J and Hannon A C 1999 J. Non-Cryst. Solids 248 1
- [44] Schlenz H, Rings S, Schmücker M, Schulmeister K, Mader W, Kirfel A and Neuefeind J 2003 J. Non-Cryst. Solids 320 133